



DRI

(Top View)

#### PRIMARY SIDE REGULATED SWITCHING MODE POWER SUPPLY CONTROLLER

**Pin Assignments** 

## Description

The AP3783 is a high performance AC/DC power supply controller for battery charger and adapter applications. The controller regulates the output voltage and current in the primary side by piece-wise Pulse Frequency Modulation (p-PFM) in discontinuous conduction mode (DCM).

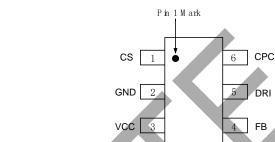
The AP3783 provides accurate constant voltage (CV), constant current (CC) and outstanding dynamic performance without requiring an opto-coupler. It also eliminates the need of loop compensation circuitry while maintaining stability.

The AP3783 provides valley turn-on function, operating frequency Jitter function (about 5.5% frequency change every 256µs) from light to full load range and 3-segment drive current to improve the power supply EMI performance. The AP3783 also has built-in fixed cable voltage drop compensation (4%, 7% and 12% of nominal system output voltage to meet various cables with different length and gauge) and adjustable line voltage compensation.

The AP3783 is packaged in SOT26.

## Applications

- Adapters/Chargers
- LED Lighting
- Standby and Auxiliary Power Supplies



## **Features**

- Less than 75mW Standby Power Consumption
- Meet Efficiency Requirement of COC Trier2
- Valley Turn-on to Reduce Switching Loss and Improve EMI
- Piece-Wise Frequency Reduction to Enhance Conversion Efficiency and Suppress Audio Noise

SOT26

- Over Voltage Protection (OVP)
- Over Temperature Protection (OTP)
- Short Circuit Protection (SCP) with Hiccup
- 3-Segment Drive Current for Radiative EMI Suppression

Operating Frequency Jitter Function for Conductive EMI Suppression

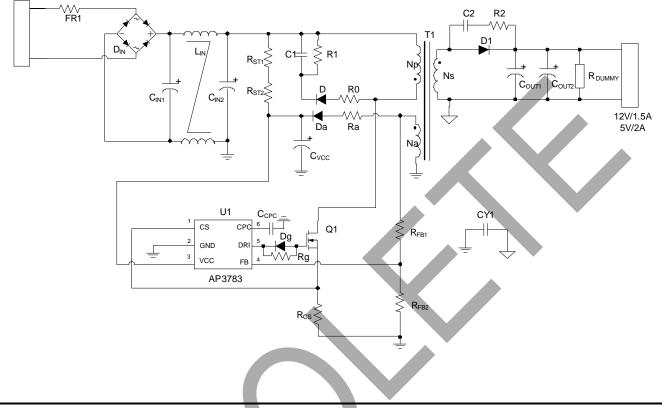
- Drive MOSFET for 5W to 30W Battery Charger/Adapter Applications
- SOT26 SMD Package Comply with Level 3 of IPC/JEDEC J-STD-033A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

- Notes:
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



# **Typical Applications Circuit**

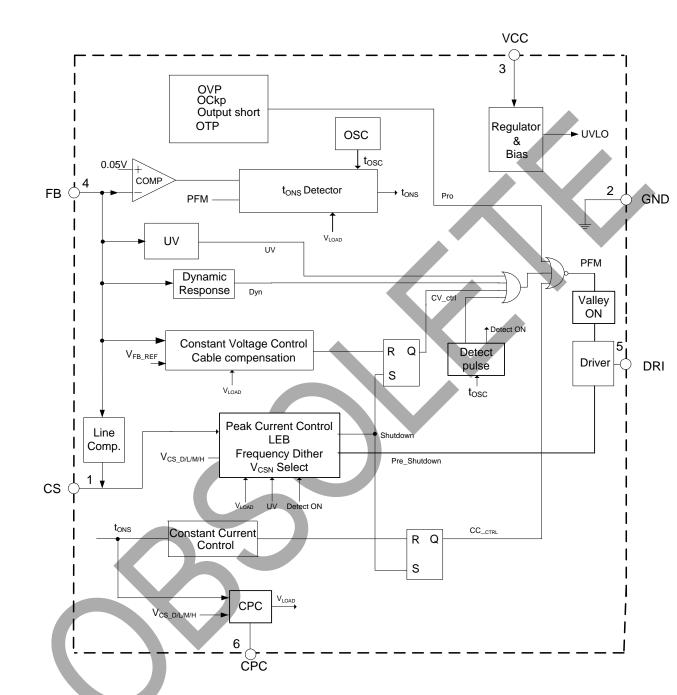


# **Pin Descriptions**

Pin Number	Pin Name	Function		
1 CS		The CS is the current sense pin of the IC. The IC will turn off the power MOSFET according to the voltage on the CS pin		
2	GND	The ground of the controller		
3	VCC	The VCC pin supplies the power for the IC. In order to get the correct operation of the IC, a capacitor with low ESR should be placed as close as possible to the VCC pin		
4	FB	The CV and CC regulation are realized based on the voltage sampling of this pin		
5	DRI	Output pin to drive external MOSFET		
6	CPC	A capacitor about 50nF should be connected to this pin. The voltage of CPC pin is linear to load of the system and it is used for the functions of cable voltage drop compensation and audio noise suppression		



# **Functional Block Diagram**





# Absolute Maximum Ratings (Note 4)

Symbol	Parameter	Rating	Unit	
Vcc	Supply Voltage	-0.3 to 35	V	
Vcs, Vcpc	Voltage on CS, CPC Pin	-0.3 to 7	V	
VFB	FB Input Voltage	-0.4 to 10	V	
ISOURCE	Source Current from OUT Pin Internally Lim		А	
TJ	Operating Junction Temperature	-40 to +150	°C	
Tstg	Storage Temperature	-65 to +150	°C	
TLEAD	Lead Temperature (Soldering, 10 sec)	+300	°C	
θյΑ	Thermal Resistance (Junction to Ambient)	mal Resistance (Junction to Ambient) 200		
500	ESD (Human Body Model)	6000	V	
ESD	ESD (Charged Device Model)	400	V	

Notes: 4. Stresses greater than those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to Absolute Maximum Ratings for extended periods can affect device reliability.

# Electrical Characteristics (@Vcc=15V, TA=+25°C, unless otherwise specified.)

Symbol	Parameters	Conditions	Min	Тур	Мах	Unit
STARTUP AN	D UVLO SECTION					
VTH_ST	Startup Threshold	-	13	15.5	18	V
VOPR(MIN)	Minimal Operating Voltage	-	6	6.8	7.6	V
STANDBY CU	RRENT SECTION					
I <sub>ST</sub>	Startup Current	V <sub>CC</sub> = V <sub>TH_ST</sub> - 1V before startup	0	0.2	0.6	μA
ICC_OPR	Operating Current	Static current @ no load	300	450	600	
DRIVING OUT	PUT SECTION					
Vgate	Gate Voltage	-	12	13	14	V
ISOURCE_L	Low Driver Source Current	-	17.5	20	22.5	mA
Isource_H	High Driver Source Current	-	100	110	120	mA
Vтн	High/Low Driver Source Current Threshold Voltage	_	6	6.5	7	V
Rsink	Sink Resistance	-	5.5	6.5	7.5	Ω



# Electrical Characteristics (Cont.) (@Vcc = 15V, TA = +25°C, unless otherwise specified.)

Symbol	Parameters	Conditions		_		
		Conditions	Min	Тур	Max	Unit
OPERATING FR	EQUENCY SECTION		1	r	r	
fs(max)	The Maximum Operating Frequency	I <sub>O(MAX)</sub> (Note 5)	-	_	60	kHz
toff(max)	Maximum Off Time		691	768	845	μs
tsample_H		57% to 100% IO(MAX)	5.2	5.8	6.4	μs
tsample_m	Control o Timo	34% to 57% I <sub>O(MAX)</sub> (Note 6)	4.3	4.8	5.3	μs
tsample_L	Sample Time	5.5% to 34% I <sub>O(MAX)</sub> (Note 6)	2.7	3	3.3	μs
tsample_d		0% to 5.5% I <sub>O(MAX)</sub> (Note 6)	1.5	1.7	1.9	μs
FREQUENCY JI	ITER SECTION					
ΔVcs/Vcs	Vcs Modulation	5.5% load to 100% IO(MAX)	4.5	5	5.5	%
fmod	Vcs Modulation Frequency	5.5% load to 100% lo(MAX)	3.6	4	4.4	kHz
CURRENT SENS	SE SECTION		-			
V <sub>CS_H</sub>	Peak Current Sense Threshold Voltage	57% to 100% I <sub>O(MAX)</sub>	828	900	972	mV
V <sub>CS_M</sub>	As Above	34% to 57% Io(MAX) (Note 6)	690	750	810	mV
V <sub>CS_L</sub>	As Above	5.5% to 34% Io(MAX) (Note 6)	414	450	486	mV
Vcs_d	As Above	0% to 5.5% I <sub>O(MAX)</sub> (Note 6)	230	250	270	mV
R <sub>LINE</sub>	Built-in Line Compensation Resistor	(Note 7)	245	260	275	Ω
t <sub>LEB</sub>	Leading Edge Blanking	V <sub>CS</sub> (Note 6)	495	550	605	ns
CONSTANT VOL	LTAGE SECTION					
VFB	Feedback Voltage	Closed loop test of VOUT	3.95	4.01	4.07	V
R <sub>FB</sub>	FB Pin Input Resistance	V <sub>FB</sub> =4V	560	700	840	kΩ
	Cable Compensation Ratio	AP3783A	6	7	8	%
Vcable /Vout%		AP3783B	3	4	5	%
/ VOUT 76		AP3783C	10	12	14	%
CONSTANT CUP	RRENT SECTION		L	L	L	
tons/tsw	Secondary Winding Conduction Duty	V <sub>FB</sub> = 3.5V	0.47	0.5	0.53	_
VALLEY-ON SEC	CTION	1		1		
tval-on	Valid Off Time of Valley-on	From the end of tons	14.4	16	17.6	μs
DYNAMIC SECT	ION	1	1	1	1	
	Under Voltage of FB Pin for Vcs_H	-	3.61	3.68	3.75	V
PROTECTION F	UNCTION SECTION					
Vfb(ovp)	Over Voltage Protection at FB Pin	_	7.1	7.5	7.9	V
Vcc(ovp)	Over Voltage Protection at VCC Pin	_	28	30	32	V
tonp(max)	Maximum Turn-on Time	_	13.5	16	25	μs
V <sub>FB(SCP)</sub>	Short Circuit Protection	V <sub>FB</sub> @ Hiccup	2.45	2.6	2.75	V
tSCP	Maximum Time under VFB(SCP)	_	115	128	141	ms
			+144	+160	+176	°C
Тотр	Shutdown Temperature	-	+144	+100	+170	0

5. The output constant-current design value, generally set to 110% to 120% of full load.
6. Guaranteed by Design. Notes:

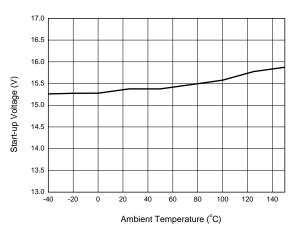
7. Line compensation voltage on CS reference: 
$$\Delta V_{CS\_REF} = 0.438 \times \frac{R_{LINE}}{R_{FB1} + R_{LINE}} \times V_{AU}$$

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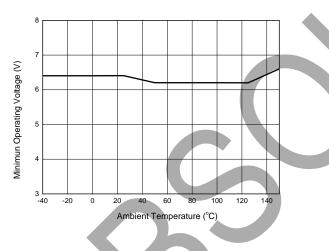


## **Performance Characteristics**

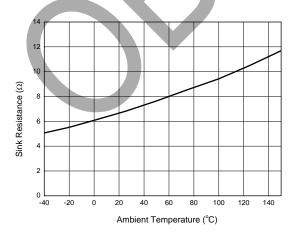


## Start-up Voltage vs. Ambient Temperature

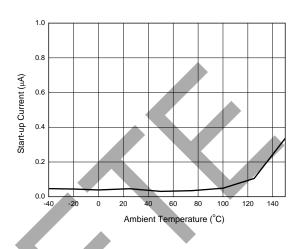
### Minimal Operating Voltage vs. Ambient Temperature



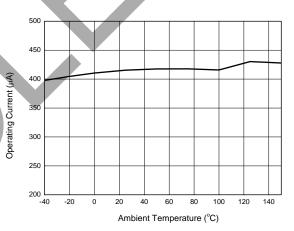
Sink Resistance vs. Ambient Temperature



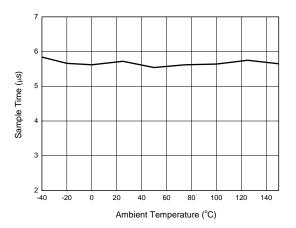
Start-up Current vs. Ambient Temperature



## **Operating Current vs. Ambient Temperature**

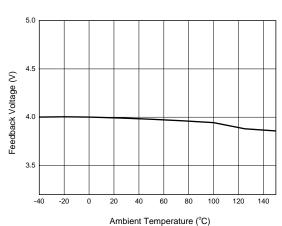


Sample Time vs. Ambient Temperature



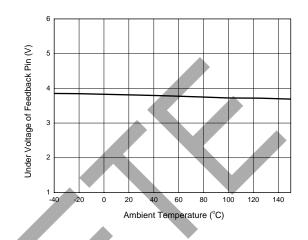


# Performance Characteristics (Cont.)

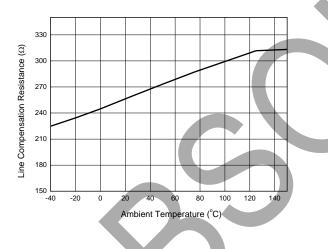


## Feedback Voltage vs. Ambient Temperature

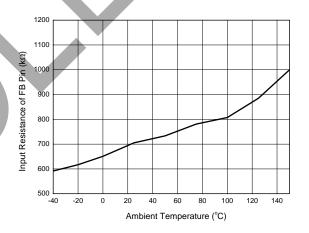
Under Voltage of FB Pin vs. Ambient Temperature



# Line Compensation Resistance vs. Ambient Temperature



# Input Resistance of FB Pin vs. Ambient Temperature





# **Operation Principle Description**

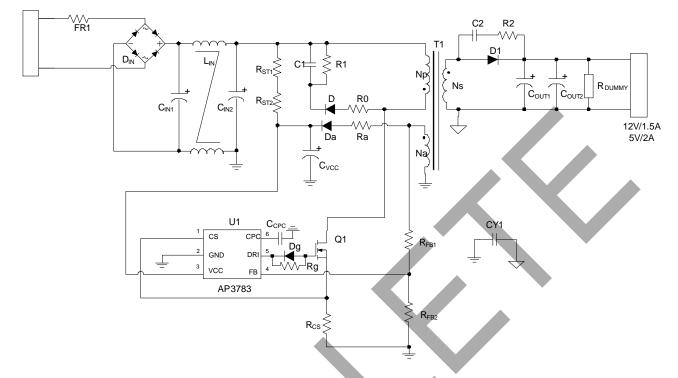


Figure 1. Typical Application Circuit of AP3783

Figure 1 is the typical application circuit of AP3783, which is a conventional Flyback converter with a 3-winding transformer---primary winding (N<sub>P</sub>), secondary winding (Ns) and auxiliary winding (N<sub>AUX</sub>). The auxiliary winding is used for providing VCC supply voltage for IC and sensing the output voltage feedback signal to FB pin.

Figure 2 shows the typical waveforms which demonstrate the basic operating principle of AP3783 application. And the parameters are defined as following.

IP----The primary side current

Is --- The secondary side current

IPK---Peak value of primary side current

IPKS---Peak value of secondary side current

Vsec---The transient voltage at secondary winding

Vs---The stable voltage at secondary winding when rectification diode is in conducting status, which equals the sum of output voltage V<sub>OUT</sub> and the forward voltage drop of diode

VAUX---The transient voltage at auxiliary winding

VA--- The stable voltage at auxiliary winding when rectification diode is in conducting status, which equals the sum of voltage VCC and the forward voltage drop of auxiliary diode

tsw --- The period of switching frequency

tonp --- The conduction time when primary side switch is "ON"

tons --- The conduction time when secondary side diode is "ON"

toFF --- The dead time when neither primary side switch nor secondary side diode is "ON"

toFFs --- The time when secondary side diode is "OFF"



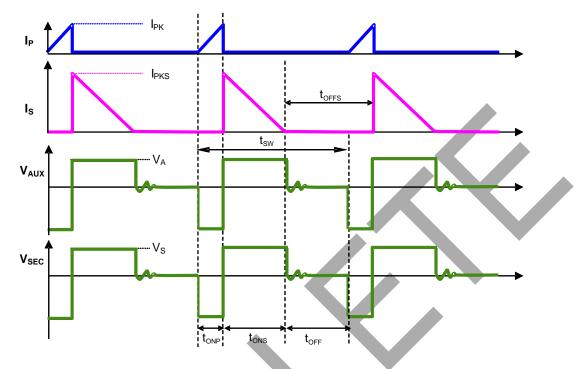


Figure 2. The Operation Waveform of Flyback PSR System

For primary-side regulation, the primary current ip(t) is sensed by a current sense resistor R<sub>CS</sub> (as shown in Figure 1). The current rises up linearly at a rate of:

$$\frac{\mathrm{dip}(t)}{\mathrm{dt}} = \frac{\mathrm{V}_{\mathrm{IN}}(t)}{\mathrm{L}_{\mathrm{M}}}$$

As illustrated in Figure 2, when the current ip(t) rises up to I<sub>PK</sub>, the switch Q1 turns off. The constant peak current is given by:

$$I_{PK} = \frac{V_{CS}}{R_{CS}}$$

The energy stored in the magnetizing inductance  $L_M$  each cycle is therefore:

(3)

(4)

(2)

(1)

$$Eg = \frac{1}{2} \times L_{M} \cdot I_{PK}^{2}$$

So the power transferring from the input to the output is given by:

$$\mathbf{P} = \frac{1}{2} \times \mathbf{L}_{\mathrm{M}} \times \mathbf{I}_{\mathrm{PK}}^{2} \times \mathbf{f}_{\mathrm{SW}}$$

Where, the f<sub>SW</sub> is the switching frequency. When the peak current I<sub>PK</sub> is constant, the output power depends on the switching frequency f<sub>SW</sub>.

#### **Constant Voltage Operation**

As to constant-voltage (CV) operation mode, the AP3783 detects the auxiliary winding voltage at FB pin to regulate the output voltage. The auxiliary winding voltage is coupled with secondary side winding voltage, so the auxiliary winding voltage at D1 conduction time is:

$$V_{AUX} = \frac{N_{AUX}}{N_{S}} \times \left(V_{O} + V_{D}\right)$$
(5)

Where the  $V_D$  is the diode forward voltage drop.

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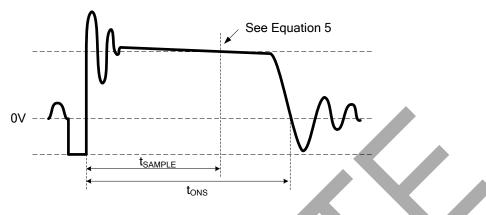


Figure 3. Auxiliary Voltage Waveform

The voltage detection point is at a constant delay time of the D1 on-time. The constant delay time is changed with the different primary peak current. The CV loop control function of AP3783 then generates a D1 off-time to regulate the output voltage.

#### **Constant Current Operation**

The AP3783 can work in constant-current (CC) mode. Figure 2 shows the secondary current waveforms.

(6)

In CC operation mode, the CC control loop of AP3783 will keep a fixed proportion between D1 on-time tons and D1 off-time torFs. The fixed proportion is

 $\frac{t_{ONS}}{t_{OFFS}} = \frac{4}{4}$ 

t<sub>offs</sub>

The relationship between the output current and secondary peak current IPKs is given by:

$$I_{OUT} = \frac{1}{2} \times I_{PKS} \times \frac{t_{ONS}}{t_{ONS} + t_{OFFS}}$$

As to tight coupled primary and secondary winding, the secondary peak current is

$$\mathbf{I}_{PKS} = \frac{\mathbf{N}_{P}}{\mathbf{N}_{S}} \times \mathbf{I}_{PK}$$

Thus the output constant-current is given by

$$I_{OUT} = \frac{1}{2} \times \frac{N_P}{N_S} \times I_{PK} \times \frac{t_{ONS}}{t_{ONS} + t_{OFFS}} = \frac{2}{8} \times \frac{N_P}{N_S} \times I_{PK}$$
(9)

Therefore, AP3783 can realize CC mode operation by constant primary peak current and fixed diode conduction duty cycle.

#### **Multiple Segment Constant Peak Current**

As to the original PFM PSR system, the switching frequency decreases with output current decreasing, which will encounter audible noise issue since switching frequency decreases to audio frequency range, about less than 20kHz.

In order to avoid audible noise issue, AP3783 uses 4-segment constant primary peak current control method. At constant voltage mode, the current sense threshold voltage is multiple segments with different loading, as shown in Figure 4, which are V<sub>CS H</sub> for high load, V<sub>CS M</sub> for medium load, V<sub>CS\_L</sub> for light load and V<sub>CS\_D</sub> for ultra light load. At constant current mode, the peak current is still V<sub>CS\_H</sub>.



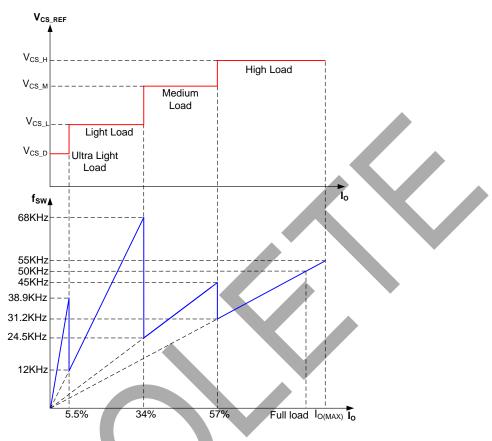


Figure 4. Multiple Segment Peak Current at CV Mode

It can be seen from Figure 4, with multiple segment peak current control, AP3783 power system can achieve good audible noise performance.

### 3-Segment Drive Current for Radiative EMI Suppression

When the power switch is turned on, a turn-on spike will occur, that worsens the radiative EMI. It is an effective way to decrease drive current before gate voltage gets to miller platform. The AP3783 uses 3-segment drive current for radiative EMI suppression, as shown in Figure 5. When gate voltage gets to 6V, the AP3783 drive current switches from low current (typical: 20mA) to high current (typical: 110mA). When the gate voltage gets to 10V, the drive current will decrease gradually to 0mA until the gate voltage goes up to the clamp voltage (13V).

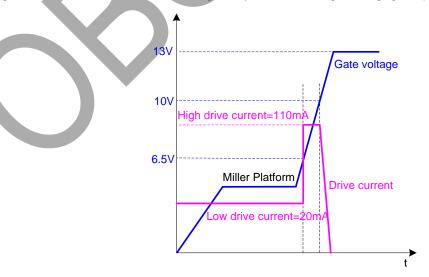


Figure 5. Drive Current and Gate Voltage



#### Leading Edge Blanking (LEB) Time

When the power switch is turned on, a turn-on spike will occur on the sense-resistor. To avoid false turn off switch, a leading-edge blanking is built in. During this blanking time, the current sense comparator is disabled and the external power switch cannot be turned off. Furthermore, due to multiple segment peak current design, the required maximum on time t<sub>ONP</sub> changes with different load conditions. Therefore the LEB time parameter also changes with different load conditions.

#### Adjustable Line Compensation and Fixed Cable Compensation

The AP3783 power system can adjust line compensation by changing the upper resistor at FB pin. The line compensation capability is increased by decreasing the resistance of the upper FB resistor.

Cable compensation is fixed in AP3783.

#### Valley Turn-on

When the off time (toFF) is lower than 16µs, AP3783 power system can work with valley turn-on. It can reduce MOSFET switching on power losses which is resulted from the equivalent output capacitance. At the same time, because of valley turn-on the switching frequency has the random jitter feature, which will be benefited for conductive EMI performance. And valley turn-on can also reduce the power switch turn-on spike current and then result in the better radiative EMI performance.

#### **Frequency Jitter**

Even though the valley turn on function can lead the random frequency jitter feature, an active frequency jitter function is added to AP3783 to ensure the frequency jitter performance in the whole loading condition. By adjusting the V<sub>CS\_REF</sub> with deviation of 5.0% every 256µs cycle, the active frequency jitter can be realized.

#### Short Circuit Protection (SCP)

Short Circuit Protection (SCP) detection principle is similar to the normal output voltage feedback detection by sensing FB pin voltage. When the detected FB pin voltage is below  $V_{FB(SCP)}$  for a duration of about 128ms, the SCP is triggered. Then the AP3783 enters hiccup mode that the IC immediately shuts down and then restarts, so that the VCC voltage changes between  $V_{TH_{ST}}$  and UVLO threshold until  $V_{FB(SCP)}$  condition is removed.

As to the normal system startup, the time duration of FB pin voltage below V<sub>FB(SCP)</sub> should be less than 18ms to avoid entering SCP mode. But for the output short condition or the output voltage below a certain level, the SCP mode will be triggered.

Figure 6 is the AP3783 normal start-up waveform that the voltage of FB pin is above  $V_{FB(SCP)}$  during  $t_{SCP}$  after  $V_{CC}$  gets to the  $V_{TH_ST}$ , which doesn't enter the SCP mode. As shown in Figure 7, Vour is short and the voltage of FB pin is lower than  $V_{FB(SCP)}$  during  $t_{SCP}$ , the AP3783 triggers the SCP and enters the hiccup mode.

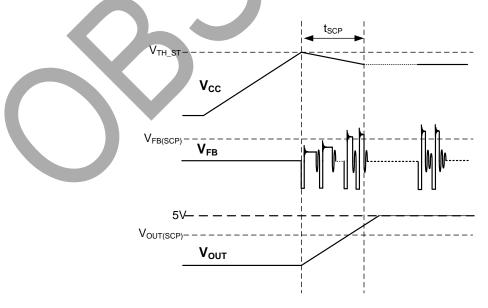


Figure 6. Normal Start-up



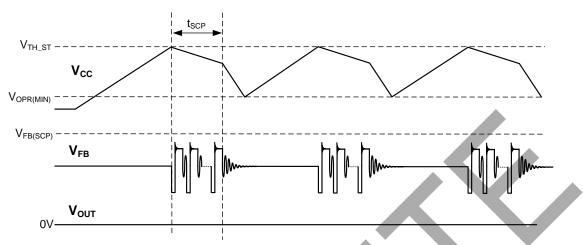


Figure 7. Short Circuit Protection (SCP) and Hiccup Mode

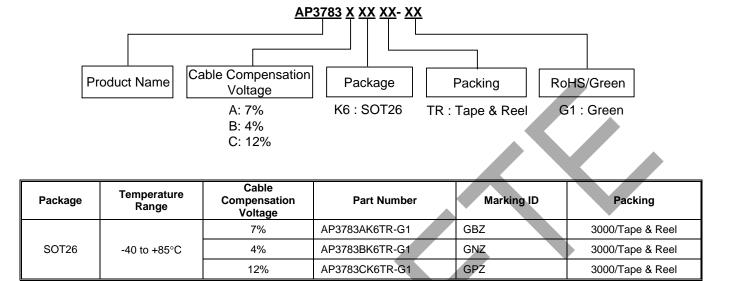
## OVP

The AP3783 includes output over-voltage protection (OVP). If the voltage at FB pin exceeds  $V_{FB(OVP)}$ , the AP3783 immediately shuts down and keeps the internal circuitry enabled to discharge the VCC capacitor to the UVLO turn-off threshold. After that, the device returns to the start state and a start-up sequence ensues.

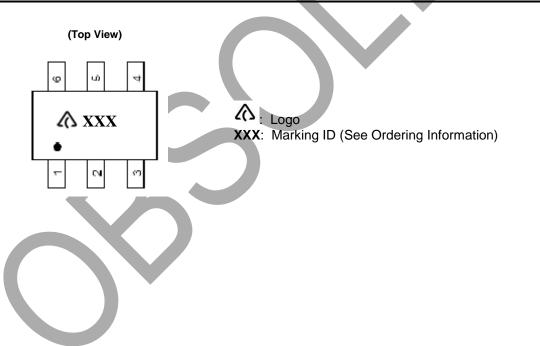
#### ОТР

If the junction temperature reaches the threshold of +160°C, AP3783 shuts down immediately. Before VCC voltage decreases to UVLO, if the junction temperature decreases to +120°C, AP3783 can recover to normal operation. If not, the power system enters restart Hiccup mode until the junction temperature decreases below +120°C.





# **Marking Information**

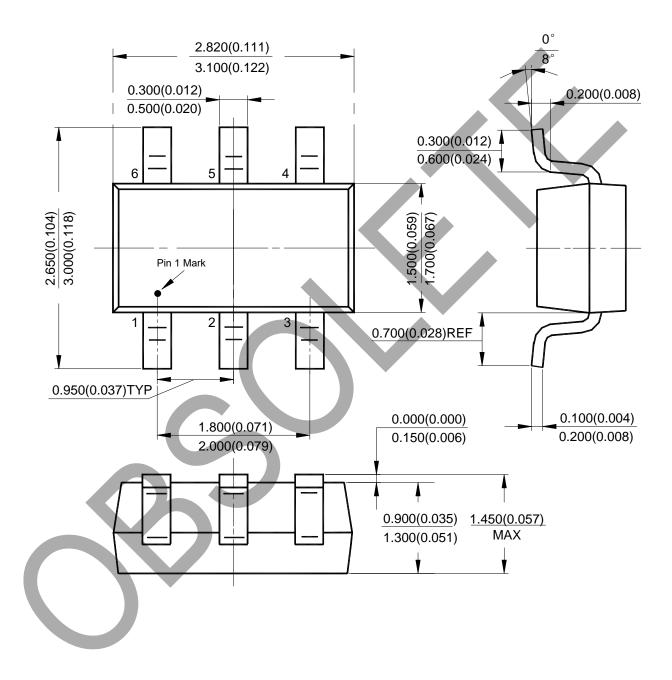




## Package Outline Dimensions (All dimensions in mm(inch).)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package Type: SOT26

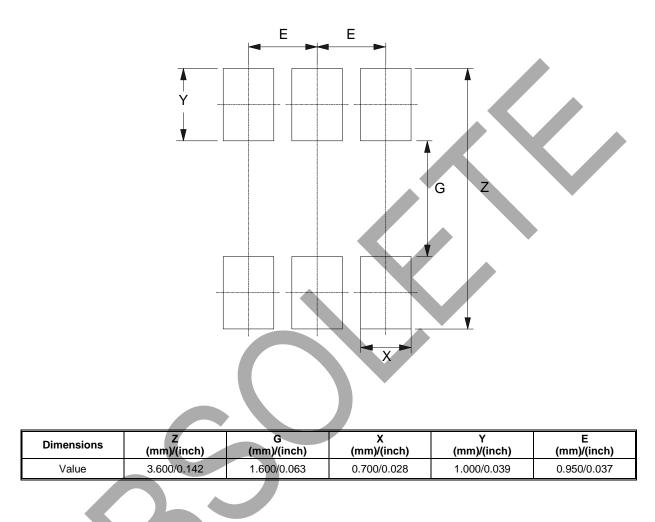




# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package Type: SOT26





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